Unit in mm

TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

TLP251

Inverter For Air Conditionor
Induction Heating
Transistor Inverter
Power MOS FET Gate Drive
IGBT Gate Drive

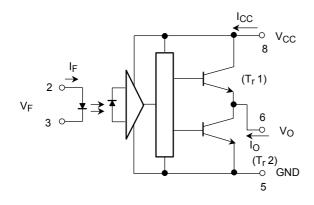
The TOSHIBA TLP251 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP251 is suitable for gate driving circuit of IGBT or power MOS FET. Especially TLP251 is capable of "direct" gate drive of lower power IGBTs. (~15A)

- Input threshold current: IF=5mA(max.)
- Supply current (ICC): 11mA(max.)
- Supply voltage (VCC): 10-35V
- Output current (I_O): ±0.4A(max.)
- Switching time (t_{pLH} / t_{pHL}): 1µs(max.)
- Isolation voltage: 2500Vrms(min.)
- UL recognized: UL1577, file no.E67349

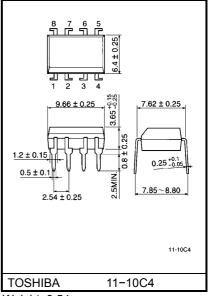
Schematic



A 0.1μF bypass capcitor must be connected between pin 8 and 5(see Note 5).

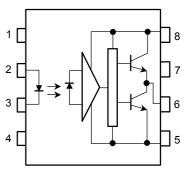
Truth Table

		Tr1	Tr2						
Input	On	On	Off						
LED	Off	Off	On						



Weight: 0.54g

Pin Configuration (top view)



- 1 : N.C.
- 2 : Anode
- 3 : Cathode
- 4 : N.C.
- 5 : Gnd 6 : V_O (Output)
- 7 : N.C.
- 8 : V_{CC}

Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	ΙF	20	mA	
	Forward current derating (Ta ≥ 70°C)		ΔI _F / ΔTa	- 0.36	mA / °C
LED	Peak transient forward current	(Note 1)	I _{FPT}	1	Α
	Reverse voltage		V _R	5	V
	Junction temperature		Tj	125	°C
	"H" peak output current (P _W ≤ 2.0μs, f ≤ 15kHz)	Іорн	- 0.4	А	
	"L" peak output current (P _W ≤ 2.0μs, f ≤ 15kHz)	(Note 2)	l _{OPL}	0.4	А
Detector	Output voltage	(Ta ≤ 70°C) (Ta = 85°C)	Vo	35 24	V
Def	Supply voltage	(Ta ≤ 70°C) (Ta = 85°C)	V _{CC}	35 24	V
	Output voltage derating (Ta ≥ 70°C)		ΔV _O / ΔTa	- 0.73	V/°C
	Supply voltage derating (Ta ≥ 70°C)		ΔV _{CC} / ΔΤα	- 0.73	V/°C
	Junction temperature	Tj	125	°C	
Oper	ating frequency	f	25	kHz	
Oper	ating temperature range	T _{opr}	-20~85	°C	
Stora	ge temperature range	T _{stg}	-55~125	°C	
Lead	soldering temperature(10s)	T _{sol}	260	°C	
Isolation voltage (AC, 1min., R.H.≤ 60%) (Note 4)			BVS	2500	Vrms

- (Note 1) Pulse width $P_W \le 1\mu s$, 300pps
- (Note 2) Expornential waveform
- (Note 3) Expornential waveform, $I_{OPH} \le -0.25A (\le 2.0 \mu s)$, $I_{OPL} \le +0.25A (\le 2.0 \mu s)$
- (Note 4) Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.
- (Note 5) A ceramic capacitor(0.1µF)should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear ampifier. Failure to provide the bypassing may impair the swiching property. The total lead length between capacitor and coupler should not exceed 1cm.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.		Unit
Input current, on	I _{F(ON)}	7	8	10		mA
Input voltage, off	V _{F(OFF)}	0	_	0.8		V
Supply voltage	V _{CC}	10	_	30	20	V
Peak output current	I _{OPH} / I _{OPL}	_	_	±0.1		Α
Operating temperature	T _{opr}	-20	25	70	85	°C

Electrical Characteristics (Ta = -20~70°C, unless otherwise specified)

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.*	Max.	Unit	
Input forward voltage		V _F	_	I _F = 10 mA , Ta = 25°C	_	1.6	1.8	V	
Temperature coefficient of forward voltage		ΔV _F / ΔTa	_	I _F = 10 mA	_	-2.0	_	mV / °C	
Input reverse current		I _R	_	V _R = 5V, Ta = 25°C	_	_	10	μA	
Input capacitance		C _T	_	V = 0 , f = 1MHz , Ta = 25°C	_	45	250	pF	
	"H" level	Іорн	3	$V_{CC} = 30V$ $V_{8-6} = 4V$	-0.1	-0.25	_	Α	
Output current	"L" level	I _{OPL}	2	(*1) $I_F = 0$ $V_{6-5} = 2.5V$	0.1	0.2	_		
Output voltage	"H" level	V _{OH}	4	V_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω , I_F = 5mA	11	13.2	_	- v	
	"L" level	V _{OL}	5	V_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω , V_F = 0.8V	_	-14.5	-12.5		
	"H" level	Іссн	_	V _{CC} = 30V, I _F = 10mA Ta = 25°C	_	7.5	_		
Complete				V _{CC} = 30V, I _F = 10mA	_	_	11	mA	
Supply current	"L" level	ICCL	_	V_{CC} = 30V, I_F = 0mA Ta = 25°C	_	8	_		
				V _{CC} = 30V, I _F = 0mA	_	_	11		
Threshould input current	"Output $L \rightarrow H$ "	I _{FLH}	_	$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, V_O > 0V$	_	1.2	5	mA	
Threshold input voltage	"Output $H \rightarrow L$ "	V _{FLH}	_	V_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω , V_O < 0V	0.8	_	_	V	
Supply voltage		V _{CC}	_		10		35	V	
Capacitance (input-output)		Cs	_	Vs = 0 , f = 1MHz Ta = 25°C	_	1.0	2.0	pF	
Resistance (input-output)		R _s	_	Vs = 500V, Ta = 25°C R.H. ≤ 60%	1×10 ¹²	10 ¹⁴	_	Ω	

^{*} All typical values are at Ta=25°C (*1): Duration of I_O time $\leq 50\mu s$

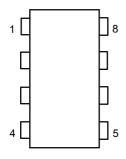
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Switching Characteristics (Ta = $-20\sim70$ °C, unless otherwise specified)

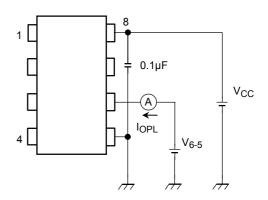
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.*	Max.	Unit
Propagation	L→H	t _{pLH}		I _F = 8mA 6 V _{CC1} = +15V, V _{EE1} = -15V	-	0.25	1.0	
delay time	H→L	t _{pHL}	6		-	0.25	1.0	
Output rise time		t _r		$R_L = 200 \Omega$	-	_	_	μs
Output fall time		t _f			_	_	_	
Common mode transient immunity at high level output		C _{MH}	7	V _{CM} = 600V, I _F = 8mA, V _{CC} = 30V, Ta = 25°C	-5000	_	_	V / µs
Common mode transient immunity at low level output		C _{ML}	7	V _{CM} = 600V, I _F = 0mA, V _{CC} = 30V, Ta = 25°C	5000	_	_	V / µs

^{*}All typical values are at Ta=25°C

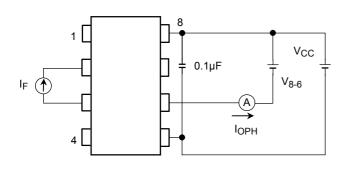
Test Circuit 1:



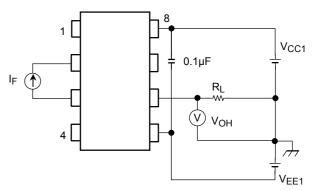
Test Circuit 2: I_{OPL}



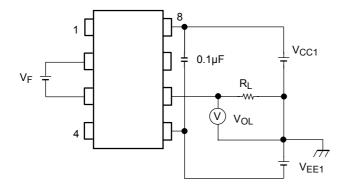
Test Circuit 3: I_{OPH}



Test Circuit 4: V_{OH}

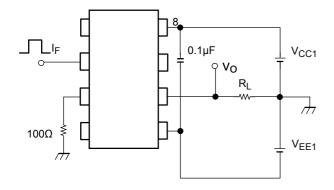


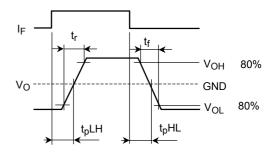
Test Circuit 5: V_{OL}



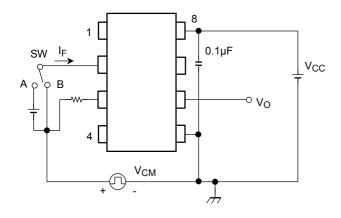
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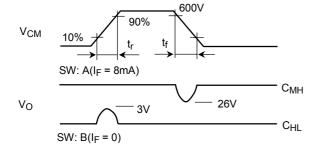
Test Circuit 6: t_{pLH}, t_{pHL}, t_r, t_f





Test Circuit 7: C_{MH}, C_{ML}

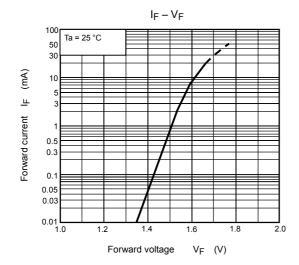


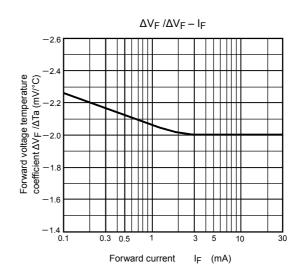


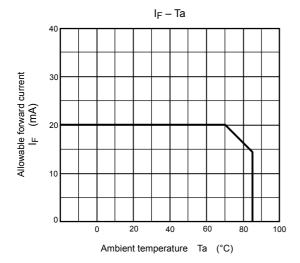
$$C_{ML} = \frac{480(V)}{t_r(\mu s)}$$

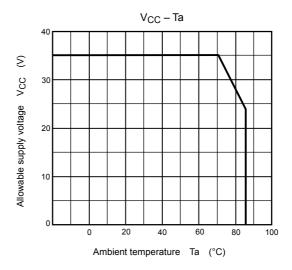
$$C_{MH} = \frac{480(V)}{t_f(\mu s)}$$

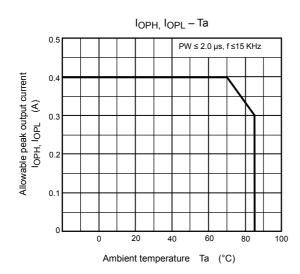
 C_{ML} (C_{MH}) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.











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